

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

# 2SC3709A

## High-Current Switching Applications

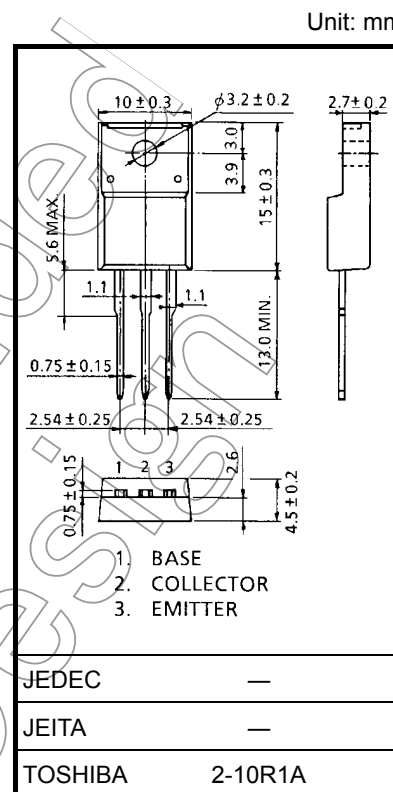
- Low collector saturation voltage:  $V_{CE(sat)} = 0.4 \text{ V (max)}$
- High-speed switching:  $t_{stg} = 1.0 \mu\text{s (typ.)}$
- Complementary to 2SA1451A

### Absolute Maximum Ratings (Tc = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	60	V
Collector-emitter voltage	$V_{CEO}$	50	V
Emitter-base voltage	$V_{EBO}$	6	V
Collector current	$I_C$	12	A
Base current	$I_B$	2	A
Collector power dissipation ( $T_c = 25^\circ\text{C}$ )	$P_C$	30	W
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature range	$T_{stg}$	-55 to 150	$^\circ\text{C}$

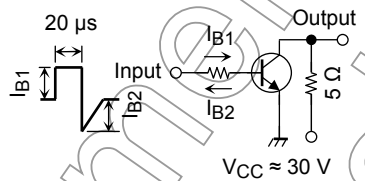
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



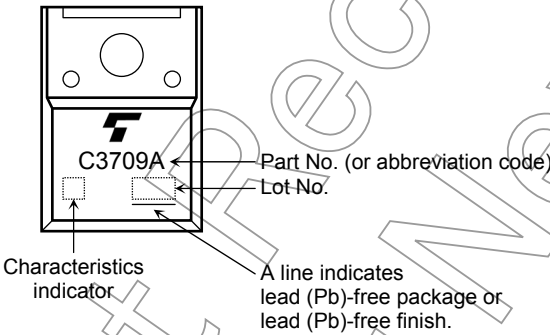
Weight: 1.7 g (typ.)

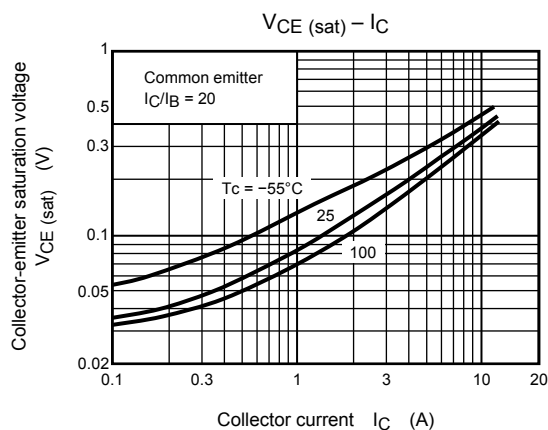
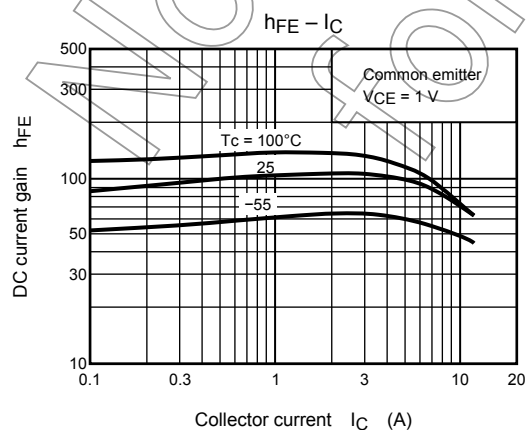
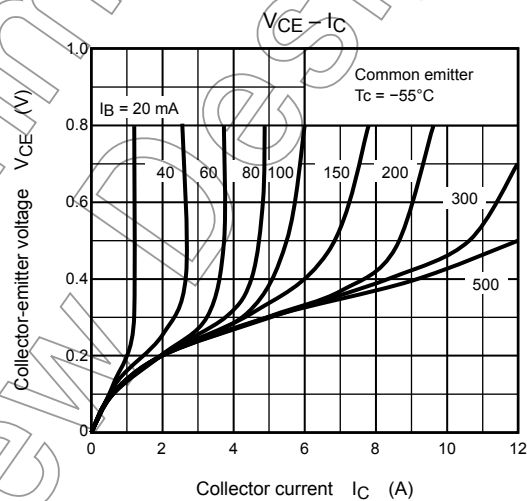
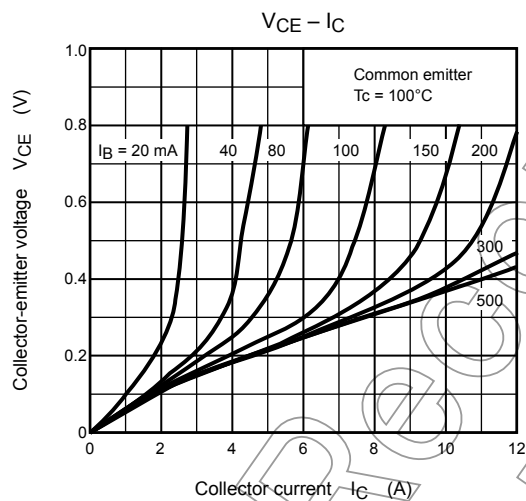
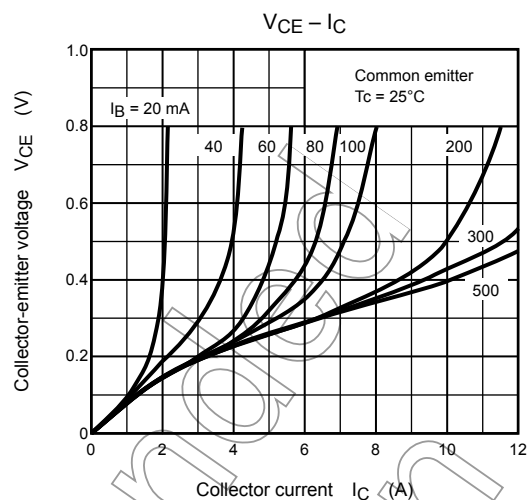
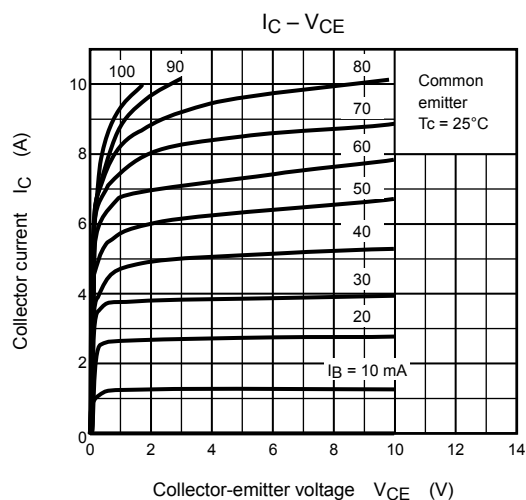
Electrical Characteristics (Tc = 25°C)

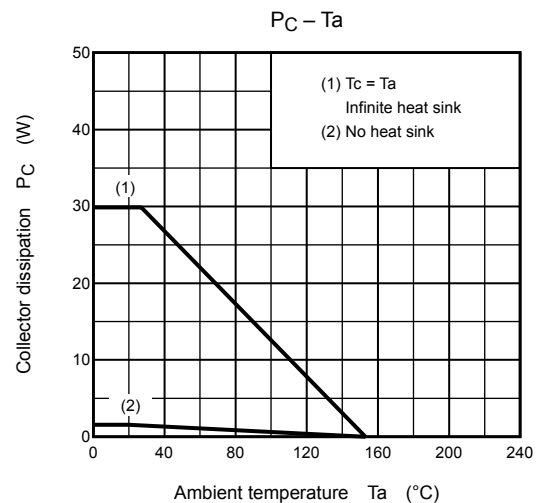
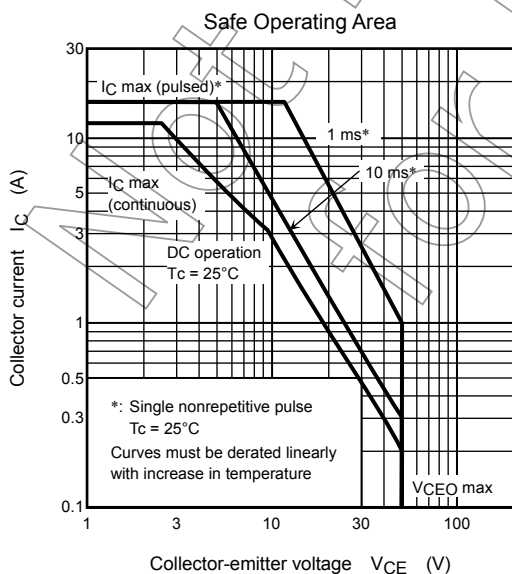
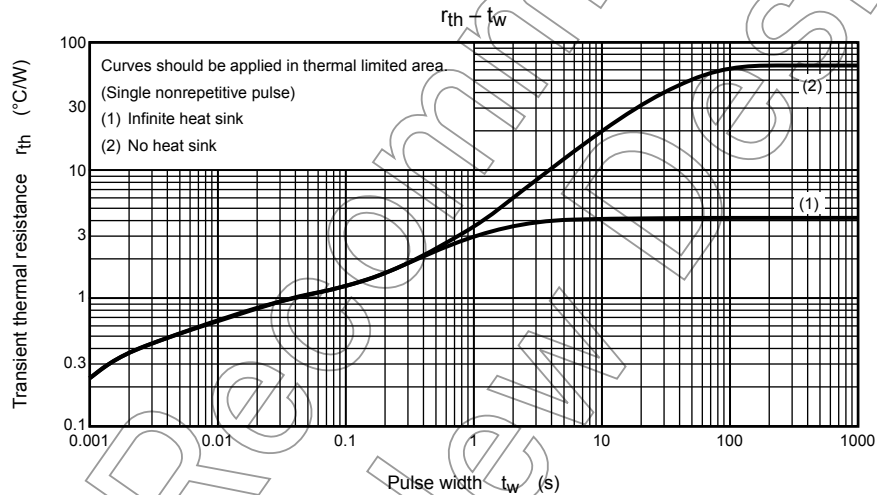
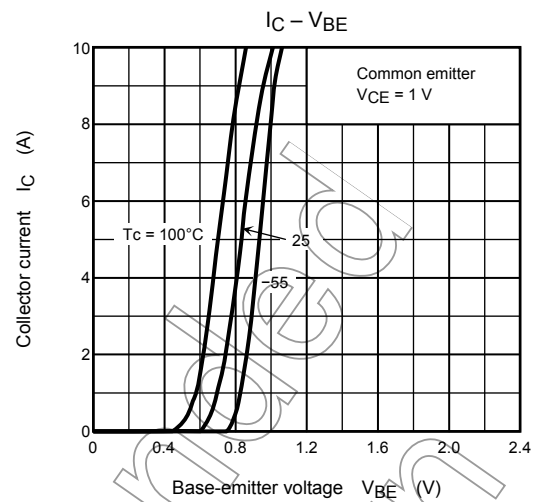
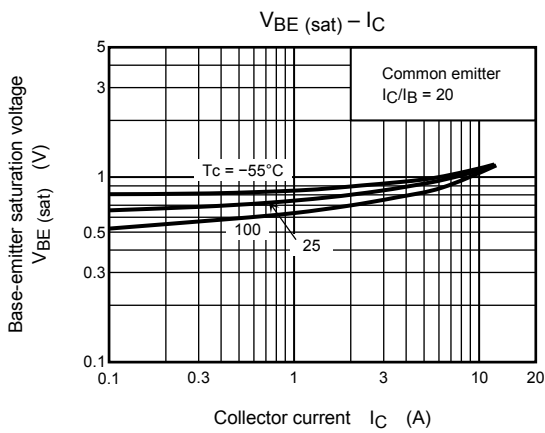
Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current		ICBO	V <sub>CB</sub> = 60 V, I <sub>E</sub> = 0	—	—	10	μA
Emitter cut-off current		IEBO	V <sub>EB</sub> = 6 V, I <sub>C</sub> = 0	—	—	10	μA
Collector-emitter breakdown voltage		V (BR) CEO	I <sub>C</sub> = 50 mA, I <sub>B</sub> = 0	50	—	—	V
DC current gain	h <sub>FE</sub> (1) (Note)		V <sub>CE</sub> = 1 V, I <sub>C</sub> = 1 A	70	—	240	
	h <sub>FE</sub> (2)		V <sub>CE</sub> = 1 V, I <sub>C</sub> = 6 A	40	—	—	
Collector-emitter saturation voltage		V <sub>CE</sub> (sat)	I <sub>C</sub> = 6 A, I <sub>B</sub> = 0.3 A	—	0.25	0.4	V
Base-emitter saturation voltage		V <sub>BE</sub> (sat)	I <sub>C</sub> = 6 A, I <sub>B</sub> = 0.3 A	—	0.9	1.2	V
Transition frequency		f <sub>T</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 A	—	90	—	MHz
Collector output capacitance		C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	—	180	—	pF
Switching time	Turn-on time	t <sub>on</sub>	 I <sub>B1</sub> = -I <sub>B2</sub> = 0.3 A, duty cycle ≤ 1%	—	0.2	—	μs
	Storage time	t <sub>stg</sub>		—	1.0	—	
	Fall time	t <sub>f</sub>		—	0.2	—	

Note: h<sub>FE</sub> (1) classification O: 70 to 140, Y: 120 to 240

Marking







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